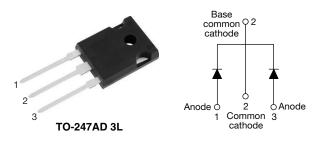
Vishay Semiconductors

Hyperfast Rectifier, 2 x 30 A FRED Pt[®] G5



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LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _{F(AV)} , per leg 30 A						
V _R	1200 V					
V _F at I _F at 125 °C	2.1 V					
t _{rr}	26 ns					
T _J max.	175 °C					
Package	TO-247AD 3L					
Circuit configuration	Common cathode					

FEATURES

- Hyperfast and optimized Q_{rr}
- · Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- FREE • 175 °C maximum operating junction temperature
- Polyimide passivation
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: TO-247AD 3L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

Polarity: as per marking device details

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage, per leg	V _{RRM}		1200	V			
Average rectified forward current, per leg	I _{F(AV)}	T _C = 101 °C, D = 0.50	30				
Repetitive peak forward current, per leg	I _{FRM}	T _C = 101 °C, D = 0.50, f = 20 kHz	60	А			
Non-repetitive peak surge current, per leg	I _{FSM}	T_{C} = 45 °C, t_{p} = 10 ms, sine wave	190				
Operating junction and storage temperature	TJ, T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER SYMBOL TEST CONDITIONS MIN. TYP. MAX. U					UNITS			
Breakdown voltage, blocking voltage, per leg	V _{BR} , V _R	I _R = 100 μA	1200	-	-			
	V _F	I _F = 30 A	-	2.6	3.3	V		
Forward voltage, per leg		I _F = 30 A, T _J = 125 °C	-	2.1	-			
Deverse leakage eurrent ner leg	I _R	$V_{R} = V_{R}$ rated	-	-	50			
Reverse leakage current, per leg		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$ -		-	500	μA		
Junction capacitance, per leg	CT	V _R = 200 V	-	17	-	pF		
Series inductance, per leg	L _S	Measured to lead 5 mm from package body	-	8	-	nH		

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HALOGEN



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$		-	26	57			
Reverse recovery time, per leg	t _{rr}	T _J = 25 °C		-	100	-	ns		
		T _J = 125 °C		-	150	-			
Poak recovery current per lea	I _{RRM}	T _J = 25 °C	$I_F = 20 A$	-	12	-	A		
Peak recovery current, per leg		T _J = 125 °C	dl _F /dt = 600 A/µs V _R = 400 V	-	22	-			
Powerze recovery charge, per leg	Q _{rr}	T _J = 25 °C		-	530	-	nC		
Reverse recovery charge, per leg		T _J = 125 °C		-	1650	-			
Boyerse recovery time, per leg	t _{rr}	T _J = 25 °C	I _F = 30 A dI _F /dt = 1000 A/μs V _R = 800 V	-	80	-	ns		
Reverse recovery time, per leg		T _J = 125 °C		-	120	-			
Deals reactions as wrant new lag	I _{RRM}	T _J = 25 °C		-	22	-	A		
Peak recovery current, per leg		T _J = 125 °C		-	37	-			
Powerea reasivery abarga, por lag	0	T _J = 25 °C		-	900	-			
Reverse recovery charge, per leg	Q _{rr}	T _J = 125 °C		-	2400	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case, per leg	R _{thJC}		-	-	0.8	°C/W		
Weight			-	6	-	g		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Marking device		Case style TO-247AD 3L	C5PX6012L					

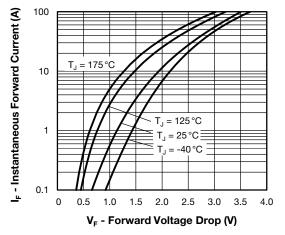


Fig. 1 - Forward Voltage Drop Characteristics, Per Leg

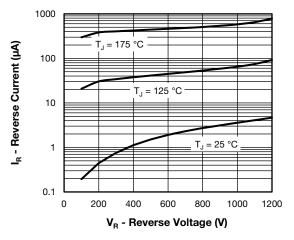


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Leg



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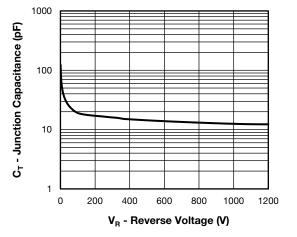


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Leg

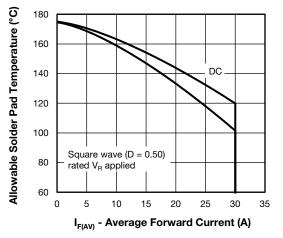


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current, Per Leg

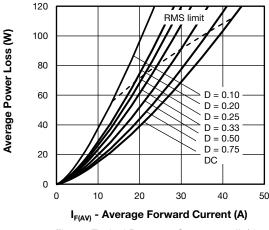


Fig. 5 - Typical Recovery Current vs. dl_F/dt

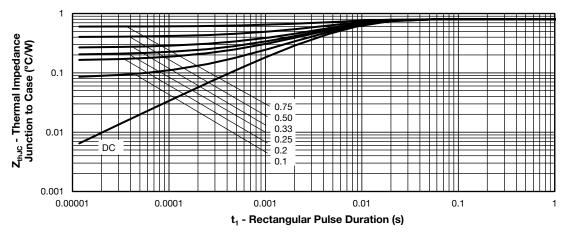


Fig. 6 - Forward Power Loss Characteristics, Per Leg



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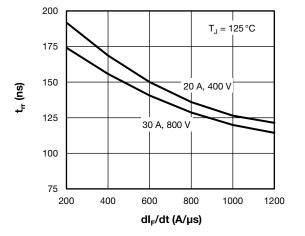


Fig. 7 - Transient Thermal Impedance, Junction to Case, Per Leg

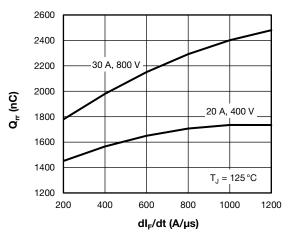


Fig. 8 - Typical Reverse Recovery Time vs. dl_F/dt, Per Leg

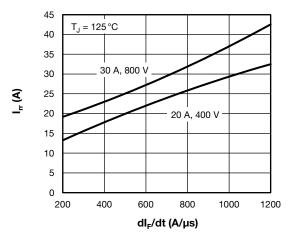


Fig. 9 - Typical Stored Charge vs. dl_F/dt, Per Leg





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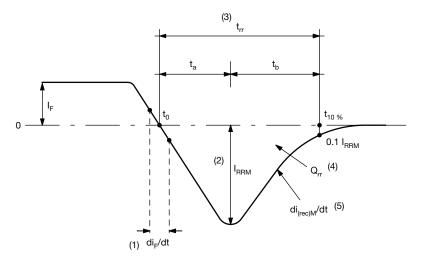


Fig. 10 - Reverse Recovery Waveform and Definitions

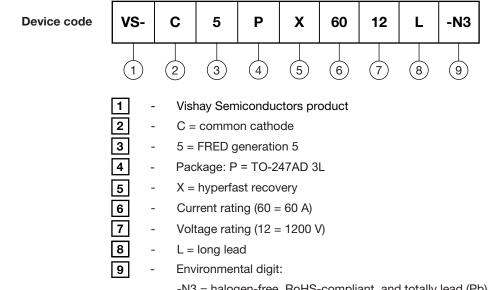
Notes

- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- ⁽²⁾ I_{RRM} peak reverse recovery current
- ⁽³⁾ t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM} ⁽⁴⁾ Q_{rr} area under curve defined by t_0 and $t_{10\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t)dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE



-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-C5PX6012L-M3	25	500	Antistatic plastic tube					
LINKS TO RELATED DOCUMENTS								
Dimensions www.vishay.com/doc?95626								
Part marking information	narking information <u>www.vishay.com/doc?95007</u>							
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TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 0.209 A 4.65 5.31 0.183 0.087 0.102 A1 2.21 2.59 1.50 2.49 0.059 0.098 A2 b 0.99 1.40 0.039 0.055 b1 0.99 1.35 0.039 0.053 b2 1.65 2.39 0.065 0.094 b3 1.65 2.34 0.065 0.092 b4 2.59 3.43 0.102 0.135 b5 2.59 3.38 0.102 0.133 с 0.38 0.89 0.015 0.035 c1 0.38 0.84 0.015 0.033 D 19.71 20.70 0.776 0.815 3 D1 13.08 -0.515 4

(4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215		
ØК	K 0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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